

CLM4121 / CLM4321

FEATURES

- High Slew Rate..... 2000V/ μ s
- Wide Bandwidth..... 180MHz
- Peak Output Current..... 300mA
- Low Supply Current..... 7mA
- No Oscillations with Capacitive Loads
- 5V to $\pm$ 15V Operation Guaranteed
- Fully Specified to Drive 50 Ω Lines

APPLICATIONS

- Coaxial Cable Driver
- Flash A/D Converter Driver
- Video DAC Buffer
- OP Amp Booster
- Video Amplifier
- High Frequency Filter
- Wide Bandwidth Signal Conditioning
- Radar
- Sonar

GENERAL DESCRIPTION

The CLM4121 family are high speed unity gain buffers that slew at 2000V/ μ s, having a small signal bandwidth of 180MHz, delivers 150mA, yet draws only 7mA supply current.

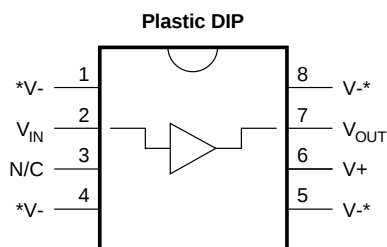
The fast slew rate, wide bandwidth, and high output drive make the CLM4121 family the ideal choice for closed loop buffer applications with wide band op amps.

These same characteristics are the excellent choices for open loop applications such as driving coaxial and switched pair cables.

ORDERING INFORMATION

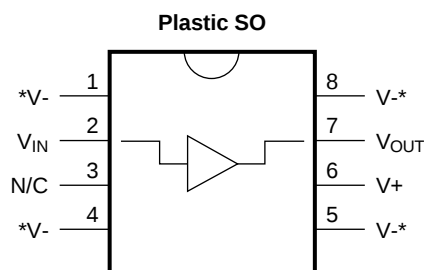
Part	Package	Temperature Range
CLM4121 N	NO8A (Plastic P Dip 8 Lead)	-40°C to 85°C
CLM4121 M	MO8B (SOIC 8 Lead)	-40°C to 85°C
CLM4321 N	NO8A (Plastic P Dip 8 Lead)	-25°C to 70°C
CLM4321 M	MO8B (SOIC 8 Lead)	-25°C to 70°C

CONNECTION DIAGRAMS



*Heat-sinking pins. Pin 1 and Pin 8 must be connected to the negative supply.

Package NO8A



*Heat-sinking pins. Pin 1 and Pin 8 must be connected to the negative supply.

Package MO8B

ABSOLUTE MAXIMUM RATINGS (Note 1)

Supply Voltage ± 20
 Input Voltage $\pm V_{\text{supply}}$
 Storage Temperature Range -65°C to $+150^{\circ}\text{C}$
 Lead Temperature
 (Soldering 10 seconds) 260°C
 Power Dissipation (Note 4)

ESD Tolerance (Note 3) $\pm 2000\text{V}$
 Thermal Resistance (θ_{JA}) (Note 6)
 N Package 50°C/W
 M Package 60°C/W
 Maximum Junction Temperature 150°C

DC ELECTRICAL CHARACTERISTICS

The following specifications apply for Supply Voltage = $\pm 15\text{V}$, $V_{\text{CM}} = 0$, $R_{\text{L}} \geq 100\text{K}\Omega$ and $R_{\text{S}} = 50\Omega$ unless otherwise noted.

Boldface limits apply for $T_{\text{A}} = T_{\text{J}} = T_{\text{MIN}}$ to T_{MAX} ; all other limits $T_{\text{A}} = T_{\text{J}} = 25^{\circ}\text{C}$.

SYMBOL	CHARACTERISTICS	TYP	CLM4121	CLM4321	UNITS	CONDITIONS
			Limit (Note 5)	Limit (Note 5)		
A_{V1}	Voltage Gain 1	0.970	0.950 0.950	0.950 0.950	V/V Min	$R_{\text{L}} = 1\text{K}\Omega$, $V_{\text{IN}} = \pm 10\text{V}$
A_{V2}	Voltage Gain 2	0.900	0.800 0.800	0.800 0.800		$R_{\text{L}} = 50\Omega$, $V_{\text{IN}} = \pm 6\text{V}$
A_{V3}	Voltage Gain 3	0.840	0.780 0.750	0.750 0.700		$R_{\text{L}} = 50\Omega$, $V^{+} = 5\text{V}$ $V_{\text{IN}} = 2V_{\text{PP}}$
V_{OS}	Offset Voltage	15	20 30	30 30	mV Max	$R_{\text{L}} = 1\text{K}\Omega$
I_{B}	Input Bias Current	1	5 7	10 10	μA Max	$R_{\text{L}} = 1\text{K}\Omega$, $R_{\text{S}} = 10\text{k}\Omega$,
R_{IN}	Input Resistance	0.5	.2	.2	$\text{M}\Omega$	$R_{\text{L}} = 50\Omega$
C_{IN}	Input Capacitance	3.5			pF	
R_{O}	Output Resistance	3	5 10	5 6	Ω Max	$I_{\text{OUT}} = \pm 10\text{mA}$
I_{S1}	Supply Current 1	7.5	10 10	10 10	mA Max	$R_{\text{L}} = \infty$
I_{S2}	Supply Current 2	2.5	5 5	5 5		$R_{\text{L}} = \infty$, $V^{+} = 5\text{V}$
V_{O1}	Output Swing 1	13.5	13.3 13	13.2 13	$\pm\text{V}$ Min	$R_{\text{L}} = 1\text{K}$
V_{O2}	Output Swing 2	12.7	10 9	10 9		$R_{\text{L}} = 100\Omega$
V_{O3}	Output Swing 3	1.8	1.6 1.3	1.6 1.5	V_{PP} Min	$R_{\text{L}} = 50\Omega$, $V^{+} = 5\text{V}$ (Note 5)
I_{OUT}	Output Current	200	140	140	mA	$V_{\text{IN}} = \pm 13\text{V}$
PSSR	Power Supply Rejection Ratio	70	60 60	60 60	dB Min	$V^{\pm} = \pm 5\text{V}$ to $\pm 15\text{V}$

AC ELECTRICAL CHARACTERISTICS

The following specifications apply for Supply Voltage = $\pm 15\text{V}$, $V_{\text{CM}} = 0$, $R_{\text{L}} \geq 100\text{K}\Omega$ and $R_{\text{S}} = 50\Omega$ unless otherwise noted.

Boldface limits apply for $T_{\text{A}} = T_{\text{J}} = T_{\text{MIN}}$ to T_{MAX} ; all other limits $T_{\text{A}} = T_{\text{J}} = 25^{\circ}\text{C}$.

SYMBOL	CHARACTERISTICS	TYP	CLM4121	CLM4321	UNITS	CONDITIONS
			Limit (Note 5)	Limit (Note 5)		
SR ₁	Slew Rate 1	4000	3500	2500	V/ μs	$V_{\text{IN}} = \pm 11\text{V}$, $R_{\text{L}} = 1\text{K}\Omega$ (Note 2)
SR ₂	Slew Rate 2	2000	1500	1000		$V_{\text{IN}} = \pm 5\text{V}$, $R_{\text{L}} = 50\Omega$ (Note 2)
SS _{BW}	Small Signal Bandwidth	180	140	100	MHz	$V_{\text{IN}} = \pm 100\text{mV}_{\text{PP}}$, $R_{\text{L}} = 50\Omega$ $C_{\text{L}} \leq 10\text{pF}$
LS _{BW}	Large Signal Bandwidth	65	55	40		$V_{\text{IN}} = \pm 11\text{V}$, $R_{\text{L}} = 1\text{K}$ $C_{\text{L}} \leq 10\text{pF}$
P _{BW}	Power Bandwidth	40	30	20		$V_{\text{IN}} = \pm 8\text{V}$, $R_{\text{L}} = 50\Omega$ $C_{\text{L}} \leq 10\text{pF}$
t _r , t _f	Rise Time Fall Time	2.0	2.5	3.5	ns	$R_{\text{L}} = 50\Omega$, $C_{\text{L}} \leq 10\text{pF}$ $V_{\text{O}} = 100\text{mV}_{\text{PP}}$
t _{pd}	Propagation Delay Time	3.0			ns	$R_{\text{L}} = 50\Omega$, $C_{\text{L}} \leq 10\text{pF}$ $V_{\text{O}} = 100\text{mV}_{\text{PP}}$
O _S	Overshoot	10			%	$R_{\text{L}} = 50\Omega$, $C_{\text{L}} \leq 10\text{pF}$ $V_{\text{O}} = 100\text{mV}_{\text{PP}}$

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. DC and AC electrical specifications do not apply when operating the device beyond its rated operating conditions.

Note 2: Slew rate is measured with 50Ω source impedance at 25°C . For accurate measurements, the input slew rate should be at least $5000\text{V}/\mu\text{s}$.

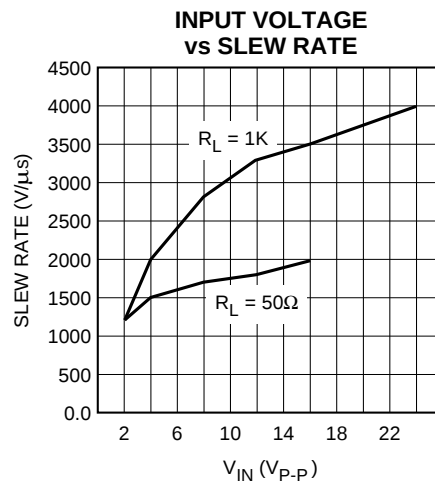
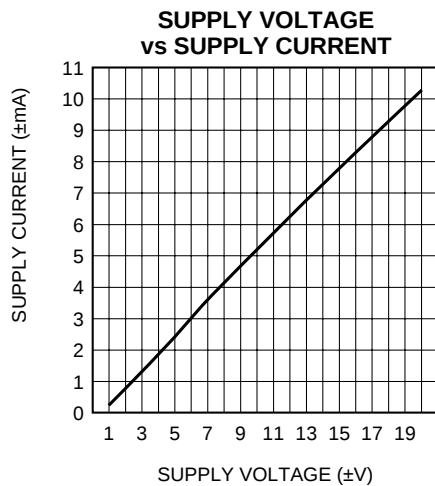
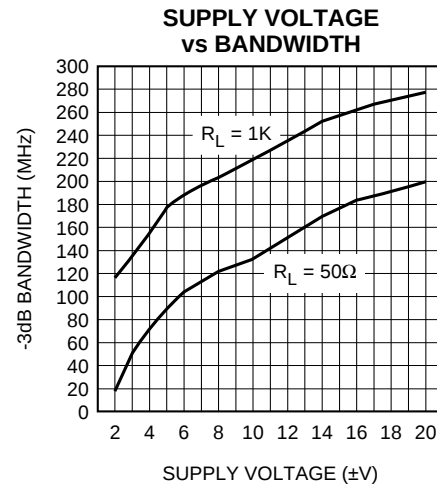
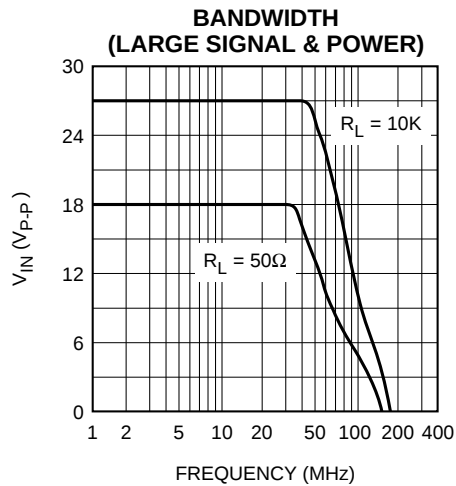
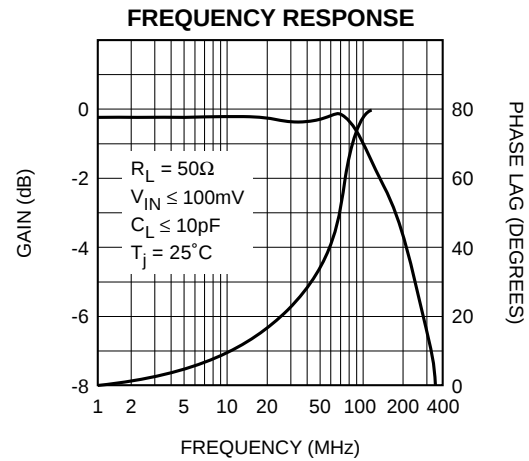
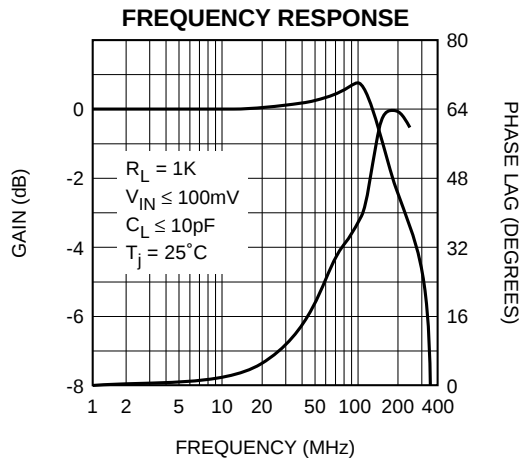
Note 3: The test circuit consists of the human body model of 120pF in series with 1500Ω .

Note 4: The maximum power dissipation is a function of $T_{\text{J(max)}}$, θ_{JA} and T_{A} . The maximum allowable power dissipation at any ambient temperature is $P_{\text{D}} = (T_{\text{J(max)}} - T_{\text{A}})/\theta_{\text{JA}}$.

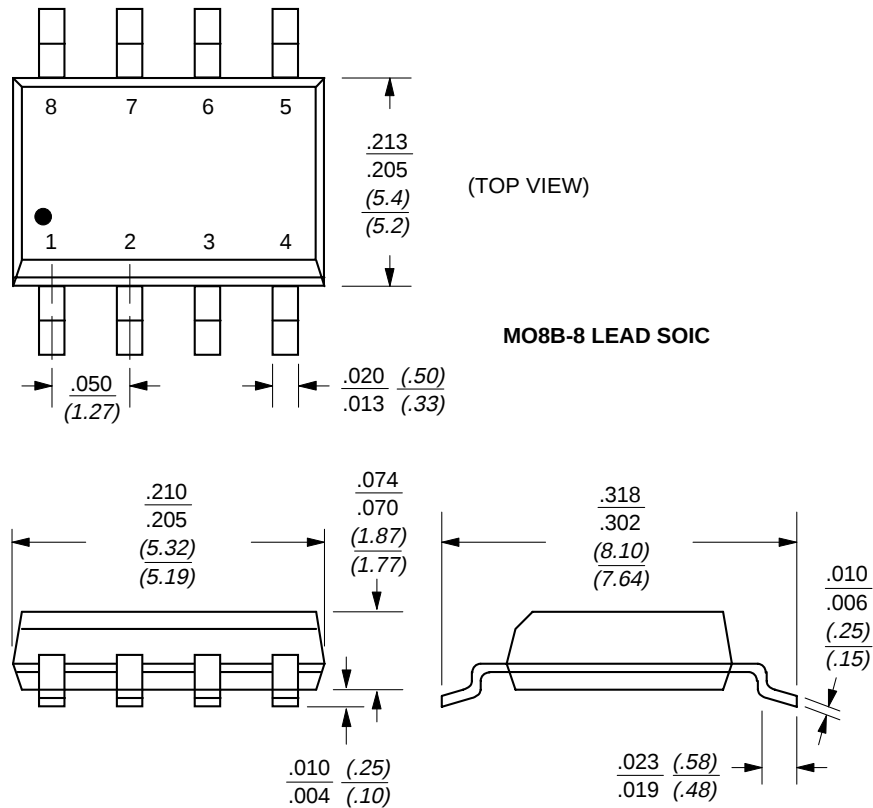
Note 5: Limits are guaranteed by testing, correlation or periodic characterization.

Note 6: For M & N package, θ_{JA} is measured by soldering the unit directly on a printed circuit board and V pins are connected to 2 square inches of 2 oz copper.

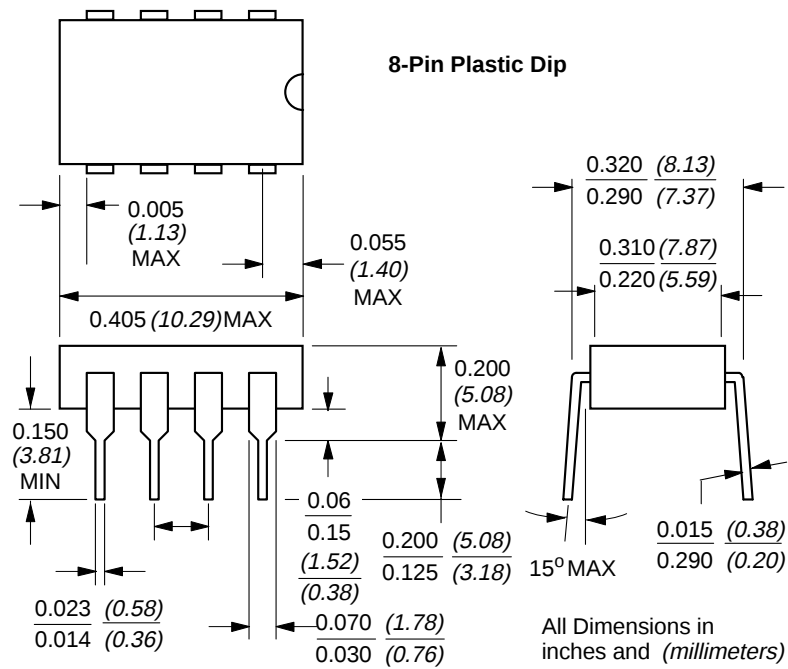
TYPICAL PERFORMANCE CHARACTERISTICS



MO8B DIMENSIONS



NO8A DIMENSIONS



Данный компонент на территории Российской Федерации

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В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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